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Z-scheme mesoporous photocatalyst constructed by modification of Sn_3O_4 nanoclusters on $g-C_3N_4$ nanosheets with improved photocatalytic performance and mechanism insight



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ABSTRACT

Antibiotic drugs have become the important organic pollutants in the water resources, the high-efficient removal of which is one of the foremost works for protecting water environment. The new Z-scheme mes- Sn_3O_4/g - C_3N_4 heterostructure was obtained in present work, compared with single g- C_3N_4 , which exhibits more superior photocatalytic performance for degrading and mineralizing tetracycline hydrochloride in water. The investigations of microstructure, physical properities and photoelectrochemical behaviors indicate that the modification effect mesoporous Sn_3O_4 on the surface of g- C_3N_4 nanosheets fabricates close heterostructure, which enlarges distinctly the specific surface area and improves dramatically the separation efficiency of charge carriers. Furthermore, the possible photocatalytic reaction mechanisms including transfer behaviors of charge carriers, generation of reactive species, degradation intermediate products of TC-HCl are also revealed in depth.

1. Introduction

Tetracycline hydrochloride (TC-HCl) as an important antibiotic drug is widely used in clinical practice all over the word, which has been a representative of organic pollutants in the water resources owing to improper and excess usage [1–10]. Most of the TC-HCl et al. antibiotics are discharged in a prototype form after the metabolism of the living organism to be accumulated in the water environments because they usually have the good water-soluble, thus resulting in bacterial variation to produce drug resistance [11–13]. However, the majorities of antibiotics are not prone to biodegradation in the water environments, so that the high-efficient removal of them has become a significant research topic and challenge in the environmental field.

In recent years, the photocatalytic degradation technology has made rapid development for purifying air and treating water pollutions, which reveals the significant application potential. Graphite phase carbon nitride $(g\text{-}G_3N_4)$ as a new semiconductor photocatalytic material has the suitable visible light range and relative narrow band gap with $\sim 2.7\,\text{eV}$, which has been one of research focal points in the

photocatalytic field of degradation of pollutants [1,14], hydrogen production [14,15] and reduction of carbon dioxide [16] etc because of its superior photocatalytic performance. However, the high recombination rate of charge carriers still is critical issue that urgently needs to be addressed, which is the major obstacle for practical application of g-C₃N₄. Therefore, the plenty strategies has been developed to improve the photocatalytic activity of g-C₃N₄, including elements doping [17], precious metal loading [18] increasing specific surface area [19], morphology control [20], heterostructure construction [21], organic group modification [22] and so on. There are many researches showing that the fabricating Z-scheme heterostructure is one of the effective strategies by means of combining g-C₃N₄ with another semiconductor, because it can more efficiently reduce the recombination rate of charge carriers [3,6]. For instance, the Z-scheme heterojunction is prepared by modifying Bi₂WO₆ on g-C₃N₄ nanosheets and NGQDs as effective collectors of charge carriers, which distinctly enhances the degradation ability of g-C₃N₄ for removing tetracycline, ciprofloxacin and oxytetracyline etc. antibiotics [3]. Beyond that, the decoration of mesoporous Co₃O₄ nanospheres assembled by monocrystal nanodots on

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 $g-C_3N_4$ can also successfully construct the Z-scheme heterostructure, improving photocatalytic performance for degrading tetracycline [6].

However, as we know that the fabrication of Z-scheme heterostructure requires that two semiconductors must have the matched energy band potential positions and close contact each other, which can ensure the shuttle and transfer of charge carriers between them. As far as g-C₃N₄ is concerned, the selectable splendid semiconductor is relative scarce for constructing Z-scheme heterostructure so it has always been a large order to find and develop new heterostructure monomer. It is found that multivalent tin oxides (eg. Sn₃O₄, Sn₂O₃, Sn₅O₆) are a kind of compounds with intermediate valence and non-stoichiometric ratio. which show some very wonderful physical and chemical properties due to the existence of oxygen vacancy. The theoretical and experimental researches indicate that Sn₃O₄ has the superior visible light responsiveness and photoelectric conversion property, which not only is a photocatalyst but also serves as monomer that forms heterostructure with other photocatalyst to improve photocatalytic performance [23-31]. According to the VB (2.69 eV) and CB (0.13 eV) potentials of Sn₃O₄ obtained in present works, we find that it can construct Z-scheme heterostructure between Sn₃O₄ and g-C₃N₄, which has hope for substantial improving photocatalytic performance of g-C₃N₄.

Therefore, in this work, the new Z-scheme mes- Sn_3O_4/g - C_3N_4 heterostructures are synthesized by simple two-step hydrothermal process. The modification of mesoporous Sn_3O_4 nanoclusters on g- C_3N_4 nanosheets obviously improves the physical, optical and photoelectric conversion properities. The photocatalytic experimental investigations indicate that the obtained Z-scheme mes- Sn_3O_4/g - C_3N_4 heterostructure dramatically enhances the photocatalytic degradation performance for removing TC-HCl in water compared with single g- C_3N_4 . In addition, the possible photocatalytic reaction mechanism is discussed in detail including transfer behaviors of charge carriers, generation of reactive species, degradation intermediate products of TC-HCl and so on. This work provides a cross-sectional practical example for improving the photocatalytic performance of g- C_3N_4 and extending application of multivalent tin oxide Sn_3O_4 in the photocatalytic materials.

2. Experimental section

2.1. Preparation and characterizations

 $SnCl_2{:}2H_2O$ (98.0%), $Na_3C_6H_5O_7{:}2H2O$ (99.0%), NaOH (96.0%), melamine (99.0%), tetracycline hydrochloride (A. R.) and distilled water etc. were used directly without any further purification in the experiments.

The g-C₃N₄ was prepared by thermal polymerization. A certain amount of melamine was put into an crucible, heating from room temperature to 550 $^{\circ}\text{C}$ with a ramping rate of $2\,^{\circ}\text{C}\,\text{min}^{-1}$ and holding for 4 h. The yellow product was collected after cooling down to room temperature naturally and grinded to the powder with an agate mortar. The preparation of Sn₃O₄ was as following. A certain percentage of SnCl₂·2H₂O, Na₃C₆H₅O₇·2H₂O of 3.6762 g were dissolved in distilled water of 12.5 mL, stirring to form a homogeneous solution A. NaOH of 0.3 g was dissolved in 12.5 mL distilled water to form B solution. Mixing A with B and stirring for 24 h, and then the mixed solution was transferred to 50 mL Teflon autoclaves and heated in an oven at 180 °C for 12 h. The produced yellow precipitates were washed using distilled water and ethanol absolute for several times, and dried in the oven at 60 °C for 12 h. The preparation of Z-scheme mes-Sn₃O₄/g-C₃N₄ heterostructure was as following. g-C₃N₄ of 0.5 g dissolved in 10 mL distilled water was performed ultrasonic treatment for 30 min, then was added a certain amount of Sn₃O₄ to continue ultrasonic treatment of 10 min, finally placed in an oven at 110 °C for 4 h. After further washing and drying, Z-scheme mes-Sn₃O₄/g-C₃N₄ heterostructure samples were obtained. In this way, by changing the amount of Sn₃O₄, the Z-scheme mes-Sn₃O₄/g-C₃N₄ heterostructures with load ratio (mass fraction) of 1%, 3%, 5%, 7% and 10% were prepared, and named as $Sn_3O_4/g-C_3N_4$ - 1, Sn_3O_4/g - C_3N_4 -2, Sn_3O_4/g - C_3N_4 -3, Sn_3O_4/g - C_3N_4 -4 and Sn_3O_4/g - C_3N_4 -5, respectively.

The powder X-ray diffraction (XRD) patterns of samples were obtained on a D/MAX-2500 diffractometer (Rigaku, Japan) using a Cu Ka radiation source ($\lambda = 1.54178 \,\text{Å}$). An S-128 4800 field emission scanning electron microscope (FESEM, Hitachi, Japan) was used to observe the morphology of samples. The transmission electron microscopy (TEM) and high-resolution transmission electron microscopy (HRTEM, Tenai G2 F30 S-Twin) were used to characterize the micromorphology and microstructure of samples. The Fourier transform infrared (FT-IR) spectra were recorded on a Bruker Vertex 70 spectrometer using KBr as the dispersion medium. Raman experiments were performed by a DXR spectrometer using the 532 nm laser and the measurements were made in back scattering geometry. The X-ray photoelectron spectroscopy (XPS) was obtained by Thermo ESCALAB 250X (America) electron spectrometer using 150 W Al Ka radiations. Specific surface area and pore size distribution were analysised by a surface area analyzer (NOVA 2200e, Quantachrome). The photocatalytic activity tests were carried out in a GHX-2 photochemical reaction apparatus (Xe light source with 420 nm cut-off filter). The UV-vis diffuse reflectance spectra (DRS) were obtained by a UV-vis-NIR spectrophotometer (Cary 5000) with scanning range of 250-900 nm. The photoluminescence (PL) spectra were carried out on the Horiba JobinYvon (FluoroMax 4) luminescence spectrometer. The time-resolved photoluminescence (TR-PL) spectra were obtained on a model FES 920 system with an excitation wavelength of 337 nm and detection wavelength of 469 nm. The stuctures of intermediates were detected by a high perfomance liquid chromatography-mass spectrometry (HPLC-MS) system with the $2.1 \times 150\,\mathrm{mm}$ Zorbax ODS column at 30 °C. Total organic carbons (TOC) were measured on a multi N/C 2100 (Analytik Jena AG, Germany) TOC analyzer. The transient photocurrent and electrochemical impedance spectroscopy (EIS) were performed on the CHI 852C electrochemical workstation (Chenhua Instruments Co. Shanghai china). The electron spin resonance (ESR) analyses were performed using a Bruker EPR A300-10/ 12 spectrometer.

2.2. Photocatalytic activity experiments

Photocatalytic activity experiments were performed under a 500 W xenon lamp with 420 nm cut-off filter. TC-HCl was used as the target molecules to evaluate the photocatalytic degradation activity of Z-scheme mes-Sn₃O₄/g-C₃N₄ heterostructure. The photocatalytic degradation experiment was as following. The photocatalyst of 50 mg was dispersed in 100 mL TC-HCl solution (10 mg L $^{-1}$) under the constant stirring. After ultrasonic treatment of 10 min, the TC-HCl solution was stirred for 30 min in the dark before the illumination to make the adsorption-desorption equilibrium between TC-HCl and photocatalyst. At a set time interval (20 min), the sample of 6 ml was taken and centrifuged for twice to remove sediment, each time for 5 min. The concentration of supernatant was determined by an UV-vis spectrophotometer (Shimadzu, USA) at 357 nm, which is the characteristic absorption wavelength of TC-HCl.

The effects of three different capture reagents on the photocatalytic degradation reaction was investigated, in which isopropylalcohol (IPA), benzoquinone (BQ) and ethylenediaminetetraacetic acid disodium salt (EDTA-2Na) of 1 mM were used as capture reagents of the hydroxyl radicals (\cdot OH), superoxide radical (\cdot O₂ $^-$) and holes (h⁺) in the photocatalytic degradation reaction of TC–HCl, respectively [32,33].

2.3. Photoelectrochemical measurements

The photocurrent and electrochemical impedance spectra tests were measured by using a standard three-electrode system. The as-prepared sample, Pt plate and saturated Ag/AgCl electrode served as the working electrodes, counter electrode and reference electrode, respectively. Na_2SO_4 aqueous solution (0.5 mol L^{-1}) was used as the electrolyte. The

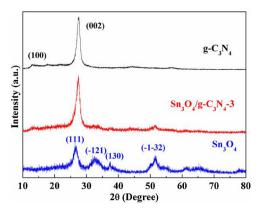


Fig. 1. XRD patterns of g-C $_3N_4$, Sn_3O_4 and Z-scheme mes- Sn_3O_4/g -C $_3N_4$ -3 heterostructure.

working electrode was prepared by the following method. The sample of 0.3 g, PVP of 0.01 g and oleic acid of 0.03 mL were dissolved in ethanol of 3 mL to form uniform suspension liquid, which was then performed spin-coated on indium tin oxide (ITO) conducting glass with the size of 15 \times 20 mm by using drop-casting method. Thereafter, the working electrode was dried in the air.

3. Results and discussion

3.1. Structure and morphology representation of the as-prepared photocatalysts

XRD is firstly used to analyze the structure and phase composition of the as-prepared samples. As can be seen from XRD pattern of g-C₃N₄ in Fig. 1, the weaker diffraction peak located at 13.1° belongs to (100) lattice planes of triazine units and the stronger diffraction peak located at 27.6° is attributed to the (002) lattice planes of interlayer stacking of aromatic segments, respectively [34,35]. In addition, XRD diffraction pattern of Sn₃O₄ in Fig. 1 is in keeping with the standard card (JCPDS NO.16-0737), where the obvious diffraction peaks are present at 27.1°, 33.0°, 37.1° and 51.7°, which correspond to (111), (-121), (130) and (-1-32) lattice planes of Sn₃O₄, respectively. No other crystal phase diffraction peaks are observed in XRD of g-C₃N₄ and Sn₃O₄, which symbolizes that they are pure without impurities generation. It is noteworthy that the weak diffraction peaks of Sn₃O₄ coming from (111), (-121) and (130) lattice planes also appear in XRD diffraction pattern of Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure besides that of g-C₃N₄ in Fig. 1, indicating the successful combination between Sn₃O₄ and g- C_3N_4 .

The morphology features of the as-prepared samples are investigated by FESEM and TEM. As FESEM image shown in Fig. 2a, the g-C₃N₄ displays an irregular bulk shape, which may result from the direct thermal polymerization of melamine molecules. Fig. 2b displays FESEM image of Sn₃O₄, showing distinct hierarchical flowers-like structure with diameter of about 500 nm. Fig. 2c is the FESEM image of Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure. We find that the plenty nanoclusters are generated from the hierarchical flowers-like of Sn₃O₄ on the g-C₃N₄ surface, which may be caused by the continuous ultrasonic and subsequent secondary hydrothermal process in the preparation. The morphology features of the as-prepared samples are further revealed by TEM images. The TEM image of g-C₃N₄ in Fig. 2d shows obviously its nanosheet structure essence, and the TEM image of Sn₃O₄ in Fig. 2e presents that the hierarchical flowers-like structure of Sn₃O₄ is self-assemblied by nanosheets. Moreover, from the TEM image in Fig. 2f, we note that lots of Sn₃O₄ nanoclusters loaded on the sureface of $g\text{-}C_3N_4$ nanosheets with only a small number of residual nanosheets. These nanoclusters are further fabricated by nanodots and exhibit obvious mesoporous structure characteristics, as revealed by TEM image

(Fig. 2g) and HRTEM image (Fig. 2h). The HRTEM image displays an interplanar spacing of 0.330 nm, which is corresponding to (111) lattice planes of $\rm Sn_3O_4$ phase [36]. Meanwhile, the HRTEM image also clearly exhibits $\rm Sn_3O_4$ nanoclusters are constructed by nanodots with size of 5–10 nm. In addition, SAED pattern in Fig. 2i shows the distinct diffraction rings, which indicates that $\rm Sn_3O_4$ nanoclusters have the polycrystalline structure. The formation of $\rm Sn_3O_4$ nanoclusters on the surface of g-C₃N₄ nanosheets is also demonstrated by HAADF image in Fig. 2j and corresponding elemental EDS mapping images in Fig.2k–n, which presents that C, N, O and Sn elements are all uniform distribution, respectively. These results demonstrate that the mesoporous $\rm Sn_3O_4$ nanoclusters are successfully modified on the surface of g-C₃N₄ nanosheets.

The FT-IR and Raman spectra of g-C₃N₄, Sn₃O₄ and Z-scheme mes-Sn₃O₄ g-C₃N₄-3 heterostructure are measured to chemical bonding information of the as-prepared samples. Comparing with the FT-IR spectra of g-C₃N₄ and Z-scheme mes-Sn₃O₄ g-C₃N₄-3 heterostructure in Fig. 3a, the characteristic peak at 808 cm⁻¹ corresponds to the vibration absorption of the triazine structural units. The multiple absorption bands from 1200 cm⁻¹ to 1700 cm⁻¹ belong to the stretching vibration modes of aromatic carbon and nitrogen heterocycles structural units [37,38]. The broad absorption peaks between $3400\,\mathrm{cm}^{-1}$ 3000 cm⁻¹ are attributed to the stretching vibration of NH groups [39,40]. Besides, referring to the FT-IR spectrum of Sn₃O₄, a weak peak is observed at 487.7 cm⁻¹ in the FT-IR spectrum of Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure, which is attributed to Sn-O vibration modes of Sn₃O₄. These indicate the successful modification of mesoporous Sn₃O₄ nanoclusters on the surface of g-C₃N₄ nanosheets. The Raman spectra of g-C $_3$ N $_4$, Sn $_3$ O $_4$ and Z-scheme mes-Sn $_3$ O $_4$ /g-C $_3$ N $_4$ -3 heterostructure are shown in Fig. 3b. According to the closer inspection of the Raman spectrum of Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure via comparing with g-C₃N₄ and Sn₃O₄, the vibration absorption peaks at 475 cm⁻¹, 705 cm⁻¹ and 1234 cm⁻¹ derived from the vibrational mode of C=N heterocycle of g-C $_3$ N $_4$ [40,41], and a group of characteristic peaks of Sn₃O₄ from 50 cm⁻¹ to 250 cm⁻¹ are also reflected in the Raman spectrum of Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure, which further confirms that the mesoporous Sn₃O₄ nanoclusters modify on the surface of g-C₃N₄ nanosheets.

To obtain information about the chemical compositions and elemental valence states of the as-prepared samples, XPS characterization of g-C₃N₄, Sn₃O₄ and Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure are performed. The survey XPS spectrum of Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure in Fig. 4a displays that Sn is obviously detected besides C, N and O elements compared to g-C₃N₄. It coincides with the EDS elements mapping result, and implies the combination between Sn₃O₄ and g-C₃N₄. The C 1 s XPS spectrum of g-C₃N₄ in Fig. 4b shows three binding energy peaks at 284.6 eV, 286.0 eV and 288.2 eV, which are attributed to C-NH2, C-(N)3 and N-C=N groups in g-C3N4, respectively [3,6]. In contrast, the binding energy peak of $C-(N)_3$ groups in Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure shifts 0.8 eV to low energy direction and located at 285.2 eV, which indicates that the strong interaction between mesoporous Sn₃O₄ nanoclusters and g-C₃N₄ nanosheets by the surface modification effect. The XPS spectrum of N 1 s of g-C₃N₄ is shown in Fig. 4c, where the binding energy peaks centered at 398.7 eV, 399.7 eV and 401.1 eV can be assigned to typical C-N-C, N-(C)₃ and C-NH₂ groups, respectively [3,6]. Similar binding energy shift also slightly takes place on N-(C)₃ groups from 399.7 eV to 399.5 eV, signifying the tight integration of mesoporous Sn₃O₄ nanoclusters modified on the surface of g-C₃N₄ nanosheets. In addition, from O 1s XPS spectra of Sn₃O₄ and Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure in Fig. 4d, the binding energy peaks at 531.0 eV and 530.0 eV are commonly ascribed to O-Sn⁴⁺ and O-Sn²⁺, respectively [29]. As shown in Fig. 4e, Sn 3d XPS spectrum of Sn₃O₄ displays clearly two splitting peaks, which drive from Sn 3d_{3/2} and Sn 3d_{5/2} states, respectively. It is worth noting that Sn 3d XPS spectra exhibit obviously asymmetrical shapes, which implies that Sn has the different chemical

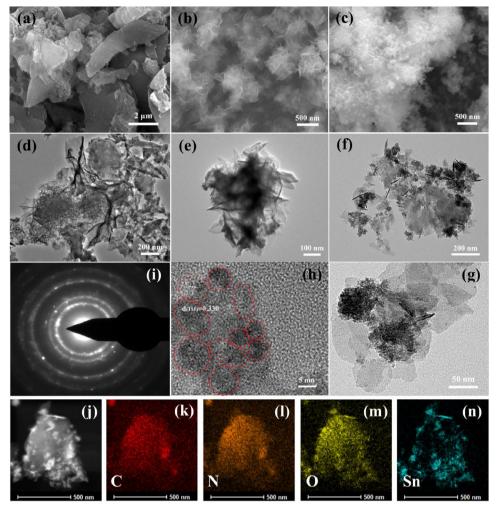


Fig. 2. FESEM images of g- C_3N_4 (a), Sn_3O_4 (b) and Z-scheme mes- Sn_3O_4/g - C_3N_4 -3 heterostructure (c), TEM images of g- C_3N_4 (d), Sn_3O_4 (e) and Z-scheme mes- Sn_3O_4/g - C_3N_4 -3 heterostructure (f–g), HRTEM image (h), SAED pattern (i), HAADF image (j) and EDS mapping (k–n) of Z-scheme mes- Sn_3O_4/g - C_3N_4 -3 heterostructure.

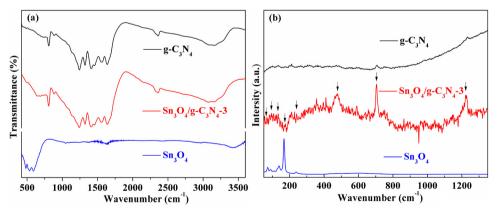


Fig. 3. FT-IR (a) and Raman (b) spectra of $g-C_3N_4$, Sn_3O_4 and Z-scheme mes- $Sn_3O_4/g-C_3N_4-3$.

states in $\rm Sn_3O_4$ crystal lattice. Meanwhile, the peaks of Sn $\rm 3d_{5/2}$ and Sn $\rm 3d_{3/2}$ can be divided into two peaks, respectively. The peaks at 486.0 eV and 494.6 eV belongs to $\rm Sn^{2+}$, while the peaks at 486.7 eV and 495.5 eV comes from $\rm Sn^{4+}$, respectively [42,43]. In contrast, these binding energy peaks take place obviously shift to the direction of high energy in the Sn XPS spectrum of Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure, which confirms the intense interaction between Sn₃O₄ and g-C₃N₄ by loading mesoporous Sn₃O₄ nanoclusters on the surface of g-C₃N₄ nanosheets, in favor of improving the photocatalytic activity and stability.

3.2. Photocatalytic degradation activity over the as-prepared photocatalysts

The photocatalytic activity of as-prepared samples is evaluated by the degradation of TC-HCl under the visible light irradiation. Fig. 5a shows the degradation dynamic curves of TC-HCl varying with illumination time over the g-C₃N₄ and Z-scheme mes-Sn₃O₄/g-C₃N₄ heterostructures with different contents of Sn₃O₄. We find that the degradation rate of g-C₃N₄ is only 23.3% within 120 min. By contrast, when the mesoporous Sn₃O₄ nanoclusters are modified on the surface of g-C₃N₄

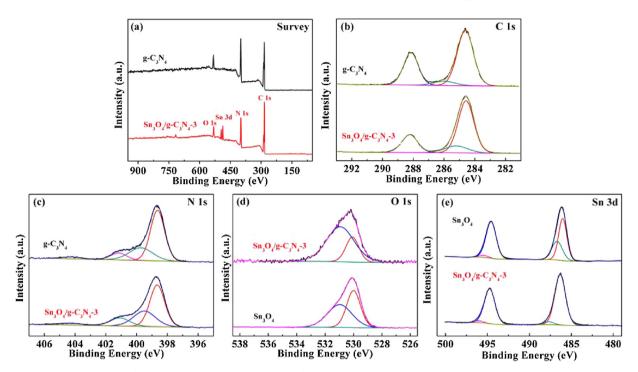


Fig. 4. XPS spectra of g-C₃N₄, Sn₃O₄ and Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure.

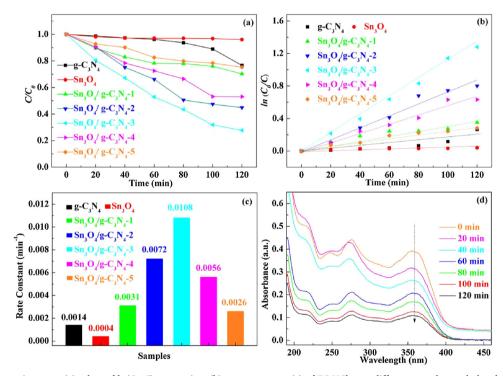


Fig. 5. Degradation dynamic curves (a), plots of $ln(C_0/C)$ versus time (b), rate constants (c) of TC-HCl over different samples, and absorbance of TC-HCl over Z-scheme mes- Sn_3O_4/g - C_3N_4 -3 heterostructure (d).

nanosheets, with increasing contents of Sn_3O_4 , the degradation rates of TC-HCl over Z-scheme mes- Sn_3O_4/g - C_3N_4 heterostructures also remarkably increase. The degradation rate of TC-HCl reaches up to maximal 72.2% within 120 min when the content of Sn_3O_4 is 3 wt%, which is about 3.1 times than that of g- C_3N_4 (23.3%). However, further increasing the content of Sn_3O_4 , the degradation rate begins to reduce, which may be caused by the shielding effect weakening light harvest ability of g- C_3N_4 and formation of recombination centers decreasing separation efficiency of electron-hole pairs originated from excess

 $\rm Sn_3O_4$ on the surface of g-C₃N₄. For the sake of making a clear quantitative comparison, the kinetic equation of first-order reaction is used to fit the photocatalytic degradation reaction of TC-HCl. The rate constants are obtained by fitting the data with the equation of $\ln(C_0/C) = kt$ (Fig. 5b) [44]. As shown in Fig. 5c, the largest rate constant k value of Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure is 0.0108 min $^{-1}$, which is about 7.7 times than that of g-C₃N₄ (0.0014 min $^{-1}$). Fig. 5d shows absorbance variation of TC-HCl solution over Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure at the photocatalytic degradation process. The

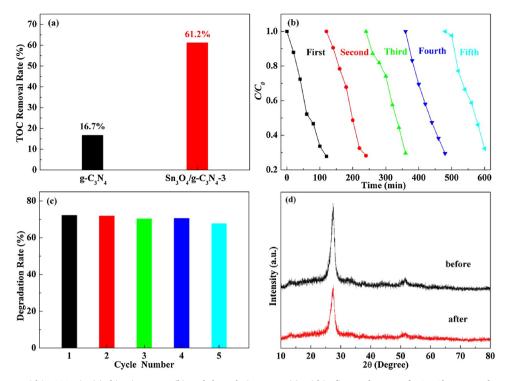


Fig. 6. TOC removal rate within 120 min (a), kinetic curves (b) and degradation rates (c) within five cycle runs of TC-HCl over Z-scheme mes- Sn_3O_4/g - C_3N_4 -3 heterostructure, XRD patterns of Z-scheme mes- Sn_3O_4/g - C_3N_4 -3 heterostructure before and after degradation reaction (c).

absorbance of TC-HCl solutions decreases obviously at the whole regions of 200 nm-400 nm after degradation process, which indirectly prove the ring structures are destroyed and completely decomposed into small organic/inorganic molecules or/and ions products [45].

Fig. 6a shows the TOC removal rates of TC within 120 min over the g-C₃N₄ and Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure. Obviously, Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure has the higher mineralization rate of 61.2%, which is far higher than that of $g-C_3N_4$ (16.7%). Furthermore, considering the stability and recyclability are important to the practical application of photocatalysts, we evaluate the stability and reproducibility of Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure by the cyclic degradation reaction of TC-HCl under the visible light irradiation. Fig. 6b-c show that the degradation rates of TC-HCl have no obviously decrease undergoing consecutive photocatalytic reaction of five times, which indicates that the Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure has superior stability and reusability. In addition, as shown in Fig. 6d, the XRD of Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure is carried out before and after the photocatalytic degradation reactions of TC-HCl. It is worth noting that the XRD pattern of the Zscheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure has almost no difference after five consecutive cycles, which further indicates that it has outstanding stability and reusability.

3.3. The influence factors of enhanced photocatalytic activity

For investigating the modification effect of mesoporous $\rm Sn_3O_4$ nanoclusters on g-C₃N₄ nanosheets to improve photocatalytic performance, the optical absorption property of as-prepared samples is firstly analyzed by UV–vis DRS. Fig. 7a displays the UV–vis DRS of g-C₃N₄, $\rm Sn_3O_4$ and Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure. It is observed that they have the strong absorption in the wavelength range of 200–450 nm. Compared with g-C₃N₄, the absorption edge of Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure exhibits distinct red-shift, which may originate from the modification effect of mesoporous $\rm Sn_3O_4$ nanoclusters on the surface of g-C₃N₄ nanosheets. It signifies that the strong interaction is formed between $\rm Sn_3O_4$ and g-C₃N₄, which is

beneficial to improve the separation efficiency of charge carriers and stability of heterostructures. In addition, on the basis of Tauc formula $(\alpha h \nu) = A(h \nu - E_{\nu})^{n/2}$ [46], the plots of $(\alpha h \nu)^2$ versus $h \nu$ are performed according to the direct band gap feature of g-C₃N₄ [47] and Sn₃O₄ (n = 1) [42]. As shown in Fig. 7b, the E_g of g-C₃N₄ is estimated to be 2.78 eV, which decreases to 2.74 eV after a small quantity of mesoporous Sn₃O₄ nanoclusters modified on its surface. It may be ascribed to coupling effect of Sn₃O₄ adjusting the surface structure of g-C₃N₄ to lead to the reduction of band gap, which suggests that Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure is easier to be excited by visible light in favor of improving photocatalytic performance. The VB and CB potentials of g-C₃N₄ and Sn₃O₄ are estimated by using the empirical equations of $E_{VB} = X - E_e + 0.5E_g$ and $E_{CB} = E_{VB} - E_g$, where E_{VB} , E_{CB} , X, $E_{\rm e}$ and $E_{\rm g}$ are the valence potential, conduction band potential, the geometric average of the absolute electronegativity of the constituent atoms, the energy of free electrons on the hydrogen scale (4.5 eV versus NHE) and band gap, respectively [48]. Therefore, based on E_g of g-C₃N₄ (2.74 eV) with X value of 4.73 eV [47] and Sn₃O₄ (2.75 eV) with X value of 5.91 eV [42] obtained from Fig. 8b, the VB and CB potentials of g- C_3N_4 are estimated to be 1.60 eV and -1.14 eV, while the VB and CB potentials of Sn₃O₄ are 2.79 eV and 0.04 eV, respectively.

Because the transport behaviors of charge carriers of photocatalyst are closely related to the fluorescence emission [48–50], we investigate the separation and transport efficiency of charge carriers by testing PL and TR-PL properties of as-prepared samples. By comparing two PL emission spectra in Fig. 8a, Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure shows low fluorescence intensity relative to g-C₃N₄, which indicates that the efficient interfacial charge transfer between g-C₃N₄ and Sn₃O₄ hinders the recombination of electron-hole pairs. Moreover, as the TR-PL curves shown in Fig. 8b, by virtue of double-exponential fitting, the achieved TR-PL lifetime (2.27 ns) of Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure is much longer than that of the g-C₃N₄ (1.19 ns), which means that the separation efficiency of the photo-generated electron-hole pairs is improved. Therefore, the photocatalytic activity of Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure is obviously enhanced by inhibiting the recombination and improving the separation

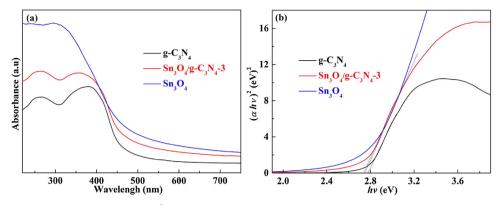
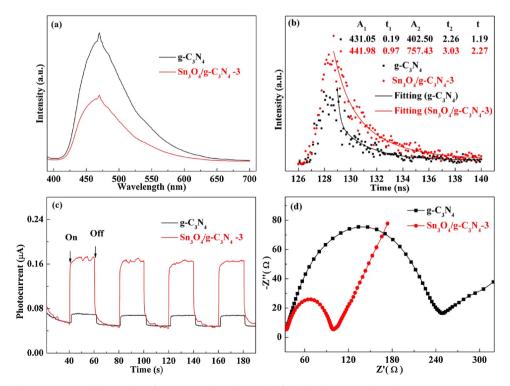


Fig. 7. UV–vis DRS (a) and plots of $(ahv)^2$ versus hv (b) of g-C₃N₄, Sn₃O₄ and Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure.

efficiency of charge carriers effectively. In general, the photocurrent response largely can reflect the separation efficiency of photo-generated carriers in semiconductor materials [51-53]. As shown in Fig. 8c, it can be seen that the g-C₃N₄ and Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure produce a stable photocurrent response at each light-off and light-on, respectively, in which the latter exhibits stronger photocurrent intensity than that of the former. It illustrates that Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure has longer lifetime and higher separation efficiency of charge carriers. This result is further evidenced by electrochemical impedance spectroscopy (EIS) of g-C₃N₄ and Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure (Fig. 8d). The arc radius of the impedance curve of Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure photoelectrode is significantly smaller than that of g-C₃N₄, which implies its surface has the smallest interfacial resistance [54-57]. In summary, Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure possesses the higher electron-hole separation efficiency and the faster interface charge transfer ability by the modification of mesoporous Sn₃O₄ nanoclusters on the surface of g-C₃N₄ nanosheets, finally improving photocatalytic performance.

In order to determine the pore structure characteristics and Brunauer-Emmett-Teller (BET) specific surface area of the as-prepared

samples, which are also the significant influence factors of photocatalytic activity. Fig. 9a shows the N2 adsorption-desorption isotherms for g- C_3N_4 and Z-scheme mes- Sn_3O_4/g - C_3N_4 -3 heterostructure. On the basis of the classification of International Union of Pure and Applied Chemistry (IUPAC) [58], the isotherms of two samples all exhibit the typical type IV with H₃ hysteresis loop in the relative pressure range of 0.4-1.0 (p/p₀), indicating that they have the mesoporous structure characteristics [59]. Meanwhile, Fig. 9b reveals that the g-C₃N₄ has a pore size distribution with 30 nm approximately. Noticeably, Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure displays the pore size distribution from 20 nm to 30 nm, which may arise from the modification effect of mesoporous Sn₃O₄ nanoclusters on the surface of g-C₃N₄ nanosheets. Moreover, the specific surface area of Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure reach up to 13.6553 m² g⁻¹, which is about 2.5 times than that of g-C₃N₄ (5.3715 m² g⁻¹). It indicates that Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure can provide more abundant active sites and adsorb more reactant molecules owing to the wide mesoporous distribution and large specific surface area, thus improving the photocatalytic performance.



 $\textbf{Fig. 8.} \ PL \ spectra \ (a), \ TR-PL \ spectra \ (b), \ transient \ photocurrent \ (c) \ and \ Nyquist \ plots \ (d) \ of \ g-C_3N_4 \ and \ Z-scheme \ mes-Sn_3O_4/g-C_3N_4-3 \ heterostructure.$

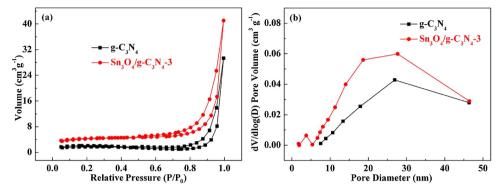


Fig. 9. N₂ adsorption-desorption isotherms (a) and pore diameter distributions (b) of g-C₃N₄ and Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure.

3.4. Insight into the mechanism of photocatalytic reaction

The photocatalytic reaction mechanism of TC-HCl is investigated in detail by virtue of the capture experiments to detect the reactive species produced during the reaction process. The kinetic curves and degradation rates of TC-HCl over Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure in the presence of different capture reagents are shown in Fig. 10a-b. It can be seen that the degradation rates of TC-HCl exhibit the certain inhibitory effect by adding reactive species capture reagents. Once the EDTA-2Na and BQ as the capture reagents of h^+ and $\cdot O_2^-$ are added to the photocatalytic reaction system, respectively, the degradation rates of TC-HCl are only 5.2% and 9.3%, which far lower than that of situation without any capture reagents (72.2%). This strong inhibiting action indicates that \boldsymbol{h}^+ and $\boldsymbol{\cdot}\boldsymbol{O_2}^-$ are main active species and the impact of h^+ is slightly higher than $\cdot O_2^-$. In addition, the degradation rate of TC-HCl decrease from 72.2% to 58.5% when IPA serves as the capture reagent of ·OH, implying that ·OH also play an important role in the degradation of TC-HCl. The produced $\cdot O_2^-$ and \cdot OH active species in the degradation process are further detected by ESR technique. As the DMPO-OH ESR spectra displayed in Fig. 10c, Zscheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure in water produces obvious four groups of signals when light on, which demonstrates that ·OH active species are generated in the photocatalytic degradation process

of TC-HCl. Similarly, four strong groups of signals of DMPO- \cdot O₂⁻ are also observed in the DMPO- \cdot O₂- ESR spectra when measuring Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure in methanol (Fig. 10d), which means \cdot O₂⁻ active species are also generated in the degradation process of TC-HCl, which is consistent with the active species capture experiments.

In order to investigate the degradation way of TC-HCl, HPLC-MS is used to analyze intermediates in the photocatalytic reaction process [5,60]. Fig. 11a-c is the mass spectra of TC-HCl over Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure when the photocatalytic reaction continues 0 min, 60 min and 120 min, respectively. According to the results in Fig. 11, we have obtained the possible degradation intermediate product structure. As shown in Fig. 12, we give some possible intermediates from B to F for degrading TC-HCl. Firstly, TC-HCl (m/ z = 445) molecules are oxidized by h⁺, ·OH and ·O₂⁻ to take place ring-opening reaction and produce compound B (m/z = 467). After that, compound C (m/z = 437) is produced by the oxidation and deamination reactions. With the detachment of the keto and amino groups, compound D (m/z = 301) is further generated from compound C. Then, the six membered ring structure is further oxidized and opened, producing compound E (m/z = 267). As the photocatalytic reaction continues, compound E is transformed into compound F (m/z = 223). Finally, as the degradation progresses, TC-HCl molecules are decomposed

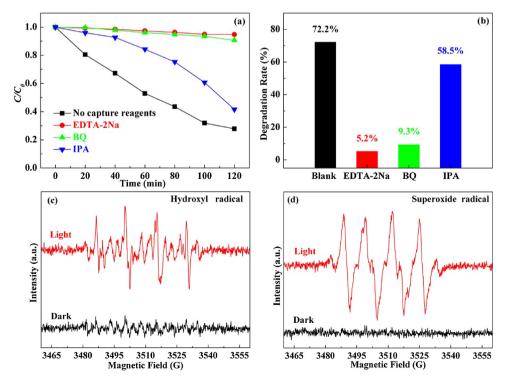


Fig. 10. Kinetic curves (a) and degradation rate (b) of TC-HCl over Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure in the presence of different capture agents, ESR spectra in the aqueous dispersion for DMPO-·OH (c) and in the methanol dispersion for DMPO-·O₂ $^-$ (d).

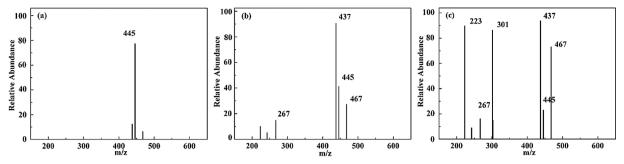


Fig. 11. Mass spectra of TC-HCl over Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure at 0 min (a), 60 min (b) and 120 min (c), respectively.

into carbon dioxide, water et al.

Based on the experimental results above, we propose the photocatalytic reaction mechanism of TC-HCl over Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure, which is shown in Fig. 13. As previously investigated, we confirm that The CB potential of Sn₃O₄ and g-C₃N₄ is 0.04 eV and -1.14 eV, respectively. It indicates that the electrons on CB of g-C₃N₄ can reduce O₂ molecules in solution to produce \cdot O₂ $^-$, but Sn₃O₄ can't achieve ·O₂ because of the standard redox potential of O_2/O_2 - with -0.046 eV [61]. Meanwhile, the lower VB potentials of Sn_3O_4 (2.79 eV) instead of g-C₃N₄ (1.60 eV) can oxidize OH $^-$ to ·OH owing to the standard redox potential of ·OH/OH with 2.3 eV [62]. Therefore, Z-scheme heterostructure should be constructed between g-C₃N₄ and Sn₃O₄ when they form composite materials. Under the visible light irradiation, the electrons on VB of g-C₃N₄ and Sn₃O₄ will transfer to CB along with holes generation on their VB, respectively. Then the electrons on CB of Sn₃O₄ and holes on VB of g-C₃N₄ quickly take place recombination at the interface of them. At the same time, the corresponding surplus electrons on CB of g-C₂N₄ and holes on VB of Sn₃O₄ migrate to their surface, respectively. The whole charge transfer between Sn₃O₄ and g-C₃N₄ can drastically improve the separation efficiency of charge carriers. Whereafter, O2 molecules dissolved in water can be adsorbed on the surface of g-C₃N₄ and react with electrons to generate $\cdot O_2^-$ or further react with H^+ to produce $\cdot OH$. In the meantime, the holes on the surface of Sn₃O₄ may also oxidize OH⁻ to produce \cdot OH as well. Finally, the holes, \cdot O₂ and \cdot OH will directly oxidize the TC-HCl molecules.

4. Conclusions

In summary, we report a Z-scheme mes- $Sn_3O_4/g\text{-}C_3N_4$ heterostructure constructed by modification of mesoporous Sn_3O_4

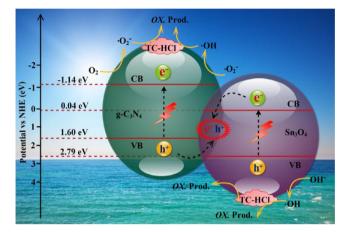


Fig. 13. Photocatalytic reaction mechanism of TC-HCl over Z-scheme mes- Sn_3O_4/g - C_3N_4 -3 heterostructure under the visible light irradiation.

nanoclusters on the surface of g-C₃N₄ nanosheets. It exhibits the highest photocatalytic performance for removing TC-HCl when the optimal load amounts of Sn_3O_4 is 5 wt%, whose degradation rate and rate constant within 120 min reach up to about 3.1 and 7.7 times than that of g-C₃N₄, respectively. The mesoporous structure and enlarged specific surface area of Z-scheme mes-Sn₃O₄/g-C₃N₄ heterostructure may provide abundant active sites and absorb more reactant molecules, in favor of enhancing photocatalytic activity. The formation of Z-scheme heterostructure between Sn₃O₄ and g-C₃N₄ inhibits effectively the recombination of charge carriers and promotes their separation, which benefits the enhancement of photocatalytic activity. The investigation of photocatalytic reaction mechanism demonstrates that ·OH and ·O₂ $^-$

Fig. 12. Possible intermediate products at the degradation process of TC-HCl over Z-scheme mes-Sn₃O₄/g-C₃N₄-3 heterostructure.

active species are generated, and they together with h^+ play the key roles in the degradation of TC-HCl. This work once again provides a new exemplification by constructing Z-scheme heterostructure by means of modification effect of mesoporous Sn_3O_4 nanoclusters on the surface of $g-C_3N_4$ nanosheets to improve photocatalytic performance of $g-C_3N_4$ for removing antibiotics pollutants.

Acknowledgments

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